

Dual D Flip-Flop with Set and Reset

MC74HC74A, MC74HCT74A

The MC74HC74A is identical in pinout to the LS74. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

This device consists of two D flip-flops with individual Set, Reset, and Clock inputs. Information at a D-input is transferred to the corresponding Q output on the next positive going edge of the clock input. Both Q and \overline{Q} outputs are available from each flip-flop. The Set and Reset inputs are asynchronous.

Features

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range:

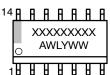
2.0 to 6.0 V (HC), 4.5 to 5.5 V (HCT)

- Low Input Current: 1.0 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the JEDEC Standard No. 7.0 A Requirements
- Chip Complexity: 136 FETs or 34 Equivalent Gates
- –Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MARKING DIAGRAMS



SOIC-14 D SUFFIX CASE 751A





TSSOP-14 DT SUFFIX CASE 948G



XXXX = Specific Device Code A = Assembly Location

WL, L = Wafer Lot Y = Year WW, W = Work Week G or = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 9 of this data sheet.

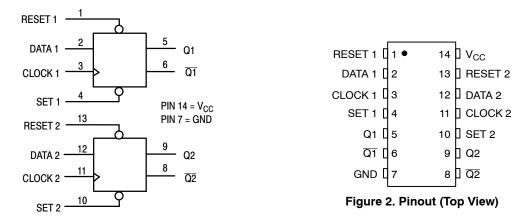


Figure 1. Logic Diagram

FUNCTION TABLE

	Inp	uts		Out	puts	
Set	Reset	Clock	Data	Q		
L	Н	Х	Х	Н	Г	
Н	L	Χ	X	L	Н	
L	L	Χ	X	H*	H*	
Н	Н		Н	Н	L	
Н	Н	_	L	L	Н	
Н	Н	L	Χ	No Cl	nange	
Н	Н	Н	Χ	No Cl	nange	
Н	Н	~	X	No Cl	nange	

^{*}Both outputs will remain high as long as Set and Reset are low, but the output states are unpredictable if Set and Reset go high simultaneously.

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
V _{IN}	DC Input Voltage		-0.5 to V _{CC} + 0.5	V
V _{OUT}	DC Output Voltage		-0.5 to V_{CC} + 0.5	V
I _{IN}	DC Input Diode Current, per Pin		±20	mA
I _{OUT}	DC Output Diode Current, per Pin		±25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins		±50	mA
I _{IK}	Input Clamp Current (V _{IN} < 0 or V _{IN} > V _{CC})		±20	mA
I _{OK}	Output Clamp Current (V _{OUT} < 0 or V _{OUT} > V _{CC})		±20	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		±150	°C
θ_{JA}	Thermal Resistance (Note 1)	SOIC-14 TSSOP-14	116 150	°C/W
P _D	Power Dissipation in Still Air at 25°C	SOIC-14 TSSOP-14	1077 833	mW
MSL	Moisture Sensitivity		Level 1	_
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V _{ESD}	ESD Withstand Voltage (Note 2)	Human Body Model Charged Device Model	> 2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Measured with minimum pad spacing on an FR4 board, using 76mm-by-114mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
МС74НС		•			
V _{CC}	DC Supply Voltage (Referenced to GND)		2.0	6.0	V
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Referenced to GND) (Note 3)		0	V _{CC}	V
T _A	Operating Free-Air Temperature		– 55	+125	°C
t _r , t _f	V	CC = 2.0 V CC = 4.5 V CC = 6.0 V	0 0 0	1000 500 400	ns
МС74НСТ					
V _{CC}	DC Supply Voltage (Referenced to GND)		4.5	5.5	V
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Referenced to GND) (Note 3)		0	V _{CC}	V
T _A	Operating Free-Air Temperature		- 55	+125	°C
t _r , t _f	Input Rise and Fall Time		0	500	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (MC74HC74A)

				G	uaranteed Lii	mit	
Symbol	Parameter	Test Conditions	V _{CC} V	–55 to 25°C	≤85°C	≤125°C	Unit
V _{IH}	Minimum High-Level Input	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	2.0	1.5	1.5	1.5	V
	Voltage	I _{OUT} ≤ 20 μA	3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			6.0	4.2	4.2	4.2	
V _{IL}	Maximum Low-Level Input	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	2.0	0.5	0.5	0.5	V
	Voltage	I _{OUT} ≤ 20 μA	3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			6.0	1.8	1.8	1.8	
V _{OH}	Minimum High-Level	V _{IN} = V _{IH} or V _{IL}					V
	Output Voltage	I _{OUT} ≤ 20 μA	2.0	1.9	1.9	1.9	
			4.5	4.4	4.4	4.4	
			6.0	5.9	5.9	5.9	
		$ I_{OUT} \le 2.4 \text{ mA}$	3.0	2.48	2.34	2.2	
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5	3.98	3.84	3.7	
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0	5.48	5.34	5.2	
V _{OL}	Maximum Low-Level	V _{IN} = V _{IH} or V _{IL}					V
	Output Voltage	I _{OUT} ≤ 20 μA	2.0	0.1	0.1	0.1	
			4.5	0.1	0.1	0.1	
			6.0	0.1	0.1	0.1	
		$ I_{OUT} \le 2.4 \text{ mA}$	3.0	0.26	0.33	0.4	
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5	0.26	0.33	0.4	
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0	0.26	0.33	0.4	
I _{IN}	Maximum Input Leakage Current	V _{IN} = V _{CC} or GND	6.0	±0.1	±1.0	±1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current (per Package)	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \mu A$	6.0	2.0	20	80	μΑ

AC ELECTRICAL CHARACTERISTICS (MC74HC74A)

			G	uaranteed Lii	mit	
Symbol	Parameter	V _{CC} V	– 55 to 25°C	≤85°C	≤125°C	Unit
f _{max}	Maximum Clock Frequency (50% Duty Cycle)	2.0	6.0	4.8	4.0	MHz
	(Figure 4)	3.0	15	10	8.0	
		4.5	30	24	20	
		6.0	35	28	24	
t _{PLH} ,	Maximum Propagation Delay, Clock to Q or Q	2.0	100	125	150	ns
t _{PHL}	(Figure 4)	3.0	75	90	120	
–		4.5	20	25	30	
		6.0	17	21	26	
t _{PLH} ,	Maximum Propagation Delay, Set or Reset to Q or Q	2.0	105	130	160	ns
t_{PHL}	(Figure 5)	3.0	80	95	130	
		4.5	21	26	32	
		6.0	18	22	27	
t _{TLH} ,	Maximum Output Transition Time, Any Output	2.0	75	95	110	ns
t_{THL}	(Figure 4)	3.0	30	40	55	
		4.5	15	19	22	
		6.0	13	16	19	
C _{in}	Maximum Input Capacitance	_	10	10	10	рF

			Typical @ 25°C, V _{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Per Enabled Output)	5.0	32	рF

^{4.} Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

TIMING REQUIREMENTS (MC74HC74A)

			Gu	Guaranteed Limit			
Symbol	Parameter	V _{CC} V	–55 to 25°C	≤ 85 °C	≤125°C	Unit	
t _{su}	Minimum Setup Time, Data to Clock (Figure 6)	2.0 3.0 4.5 6.0	80 35 16 14	100 45 20 17	120 55 24 20	ns	
t _h	Minimum Hold Time, Clock to Data (Figure 6)	2.0 3.0 4.5 6.0	3.0 3.0 3.0 3.0	3.0 3.0 3.0 3.0	3.0 3.0 3.0 3.0	ns	
t _{rec}	Minimum Recovery Time, Set or Reset Inactive to Clock (Figure 5)	2.0 3.0 4.5 6.0	8.0 8.0 8.0 8.0	8.0 8.0 8.0 8.0	8.0 8.0 8.0 8.0	ns	
t _w	Minimum Pulse Width, Clock (Figure 4)	2.0 3.0 4.5 6.0	60 25 12 10	75 30 15 13	90 40 18 15	ns	
t _w	Minimum Pulse Width, Set or Reset (Figure 5)	2.0 3.0 4.5 6.0	60 25 12 10	75 30 15 13	90 40 18 15	ns	
t _r , t _f	Maximum Input Rise and Fall Times (Figure 4)	2.0 3.0 4.5 6.0	1000 800 500 400	1000 800 500 400	1000 800 500 400	ns	

DC ELECTRICAL CHARACTERISTICS (MC74HCT74A)

				Gu	aranteed Li	imit	
Symbol	Parameter	Test Conditions	v _{cc}	–55 to 25°C	≤ 85 °C	≤ 125°C	Unit
V _{IH}	Minimum High-Level Input Voltage	$V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ $ I_{out} \le 20 \mu\text{A}$	4.5 5.5	2.0 2.0	2.0 2.0	2.0 2.0	V
V _{IL}	Maximum Low-Level Input Voltage	$V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ $ I_{out} \le 20 \mu\text{A}$	4.5 5.5	0.8 0.8	0.8 0.8	0.8 0.8	V
V _{OH}	Minimum High-Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \ \mu\text{A}$	4.5 5.5	4.4 5.4	4.4 5.4	4.4 5.4	V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 4.0 \text{ mA}$	4.5	3.98	3.84	3.7	
V _{OL}	Maximum Low-Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \mu\text{A}$	4.5 5.5	0.1 0.1	0.1 0.1	0.1 0.1	V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 4.0 \text{ mA}$	4.5	0.26	0.33	0.4	
l _{in}	Maximum Input Leakage Current	V _{in} = V _{CC} or GND	5.5	± 0.1	± 1.0	± 1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $I_{out} = 0 \mu A$	5.5	2.0	20	80	μΑ
ΔI_{CC}	Additional Quiescent Supply Current	V _{in} = 2.4 V, Any One Input V _{in} = V _{CC} or GND, Other Inputs		≥-55°C	25°C	to 125°C	
		$I_{out} = 0 \mu A$	5.5	2.9		2.4	mA

AC ELECTRICAL CHARACTERISTICS (MC74HCT74A)

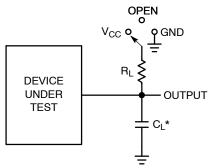
		Gı			
Symbol	Parameter	–55 to 25°C	≤ 85 °C	≤ 125°C	Unit
f _{max}	Maximum Clock Frequency (50% Duty Cycle) (Figure 4)	30	24	20	MHz
t _{PLH} , t _{PHL}	Maximum Propagation Delay, Clock to Q or $\overline{\mathbf{Q}}$ (Figure 4)	24	30	36	ns
t _{PLH} , t _{PHL}	Maximum Propagation Delay, Set or Reset to Q or Q (Figure 5)	24	30	36	ns
t _{TLH} , t _{THL}	Maximum Output Transition Time, Any Output (Figure 4)	15	19	22	ns
C _{in}	Maximum Input Capacitance	10	10	10	pF

		Typical @ 25°C, V _{CC} = 5.0 V	1
C _{PD}	Power Dissipation Capacitance (Per Enabled Output)*	32	pF

^{5.} Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

TIMING REQUIREMENTS (MC74HCT74A)

				(Guarante	ed Limi	it		
				5 to i°C	≤ 8	5°C	≤ 12	5°C	
Symbol	Parameter	Fig.	Min	Max	Min	Max	Min	Max	Units
t _{su}	Minimum Setup Time, Data to Clock	6	15		19		22		ns
t _h	Minimum Hold Time, Clock to Data	6	3		3		3		ns
t _{rec}	Minimum Recovery Time, Set or Reset Inactive to Clock	5	6		8		9		ns
t _w	Minimum Pulse Width, Clock	4	15		19		22		ns
t _w	Minimum Pulse Width, Set or Reset	5	15		19		22		ns
t _r , t _f	Maximum Input Rise and Fall Times	4		500		500		500	ns



Test	Switch Position	CL	R _L
t _{PLH} / t _{PHL}	Open	50 pF	1 kΩ
t _{PLZ} / t _{PZL}	V _{CC}		
t _{PHZ} / t _{PZH}	GND		

Figure 3. Test Circuit

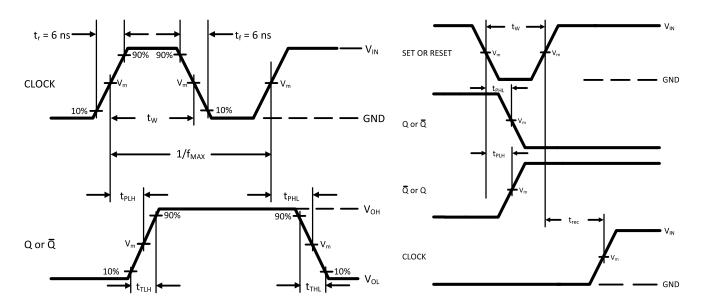


Figure 4. Figure 5.

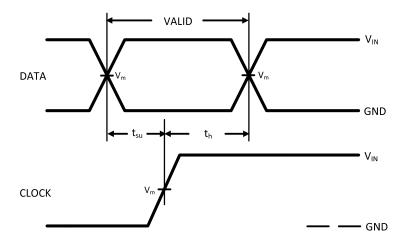


Figure 6.

Device	V _{IN} , V	V _m , V
MC74HC74A	V _{CC}	50% x V _{CC}
MC74HCT74A	3 V	1.3 V

 $^{^{\}star}C_{L}$ Includes probe and jig capacitance

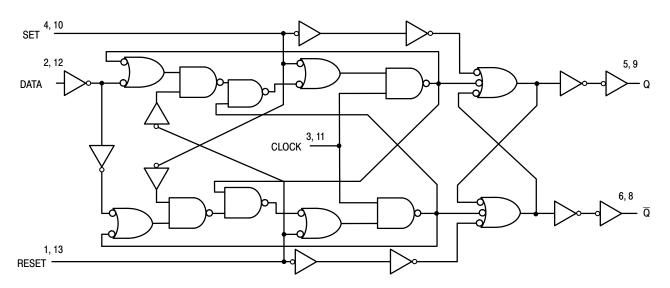


Figure 7. Expanded Logic Diagram

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74HC74ADG	HC74AG	SOIC-14	55 Units / Rail
MC74HC74ADR2G	HC74AG	SOIC-14	2500 / Tape & Reel
MC74HC74ADTR2G	HC 74A	TSSOP-14	2500 / Tape & Reel
MC74HC74ADTR2G-Q*	HC 74A	TSSOP-14	2500 / Tape & Reel
MC74HCT74ADG*	HCT74AG	SOIC-14	55 Units / Rail
MC74HCT74ADR2G*	HCT74AG	SOIC-14	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

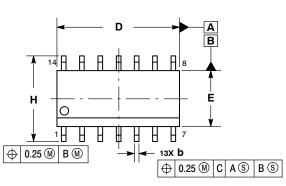
^{*-}Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

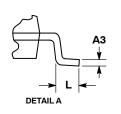


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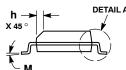
SOIC-14 NB CASE 751A-03 ISSUE L

DATE 03 FEB 2016





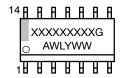




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 - DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
 - MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
АЗ	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
Е	3.80	4.00	0.150	0.157
е	1.27 BSC		0.050 BSC	
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0 °	7°	0 °	7°

GENERIC MARKING DIAGRAM*



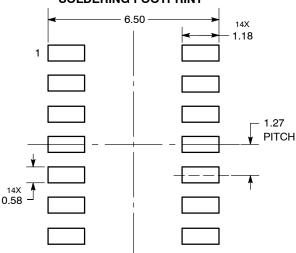
XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year = Work Week

WW = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

C SEATING PLANE

STYLES ON PAGE 2

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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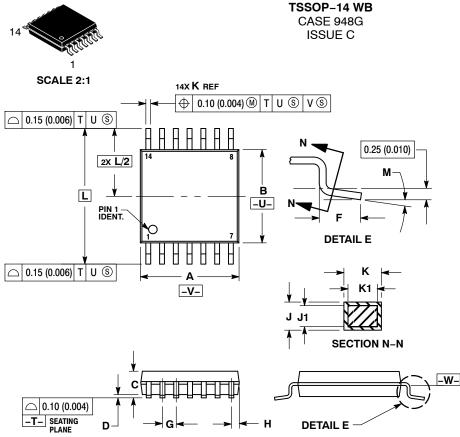
DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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DATE 17 FEB 2016

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

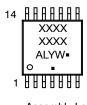
 3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR DEFERENCE ONLY
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252	BSC
М	o°	8 °	0 °	8 °

GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot Υ = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location) *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

so	OLDERING FOOT	PRINT
~	7.06 —	-
1		
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		0.65
<u> </u>	1	
0.36 T	14X	

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DESCRIPTION:	TSSOP-14 WB	•	PAGE 1 OF 1

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